Dynamical Observation of Bamboo-like Carbon Nanotube Growth

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ABSTRACT

The growth dynamics of bamboo-like multiwalled carbon nanotubes (BCNTs) via catalytic decomposition of C₂H₂ on Ni catalyst at 650 °C was observed in real time using an in situ ultrahigh vacuum transmission electron microscope. During BCNT growth, the shape of the catalyst particle changes constantly but remains metallic and crystalline. Graphene sheets (bamboo knots) within the nanotube preferentially nucleate on the multistep Ni−graphite edges at the point where the graphene joins the catalyst particle, where it is stabilized by both the graphene walls and the Ni catalyst surface. The growth of a complete inner graphene layer growth prior to contraction of the Ni catalyst particle due to restoring cohesive forces will result in a complete BCNT knot whereas partial growth of the inner wall will lead to an incomplete BCNT knot.

The extraordinary thermal, electronic, magnetic, and mechanical properties of carbon nanotubes (CNTs) make them important materials for applications such as nanoelectronic devices, hydrogen storage devices, biological probes, atomic probes, optical switches, and fuel cells.1−4 Depending on the arrangement of the graphene layers and the angle of the graphene layers to the tube axis, tubular carbon based nanostructures can be classified into four subgroups, namely, single-walled carbon nanotubes (SWNTs), multiwalled nanotubes (MWNTs), bamboo-like carbon nanotubes (BCNTs), and cup-stacked carbon nanofibers (CNFs).5−9

Despite substantial strides made in the development of new CNT based devices and prototypes for nanotechnological applications, a complete understanding of the growth mechanism of these C nanostructures is lacking as many of the proposed theories remain to be verified.10−14 Among the common methods used for fabrication of CNTs, chemical vapor deposition (CVD) of CNTs, chemical vapor deposition (CVD) of CNTs is the process of choice for industrial adoption due to its scalability and low cost. In CVD growth, the C product formed is strongly dependent on the growth temperature, type of catalyst, size of the catalyst particles, and the gaseous precursors.6−8 Often, CVD growth using the same experimental growth conditions yields different morphologies or types of tubes, making complete and detailed understanding of the reactions difficult. This is further exacerbated by the ambient pressure or low vacuum growth conditions that convolute data with contaminants, thus making the growth process more complex to comprehend.

For C-based nanostructures, understanding growth pathways is therefore the basis for large-scale industrial production of high-quality CNTs with controlled helicity, length, and diameters for technological applications. We designed in situ experiments to replicate/mimic the real CVD environment, less the contamination effect by operating in a system with ultrahigh vacuum (UHV) base pressure. In situ UHV transmission electron microscopy (TEM) is an ideal tool for conducting growth experiments due to the possibility of real time observation at the nanometer scale.15 It allows us to investigate the mechanisms and growth kinetics of CNT quantitatively. Helveg et al. is the first group to use in situ TEM to observe the growth of carbon nanotubes.16 Several in situ TEM studies of carbon nanostructures have been reported recently.17−20 Using in situ UHV TEM, we recently provided direct dynamical evidence that SWNT formation is caused by the nucleation of a hemispherical cap, with an activation energy of E_a ~2.7 eV, followed by a strain relaxation driven shape transition to a tubular growth mode.21

In this Letter, we present high-resolution imaging of typical BCNT structures which are produced in a conventional furnace, as well as the real-time observations of the BCNT growth process on a Ni−MgO catalyst by catalytic decomposition of C₂H₂ in an in situ UHV TEM. The CNT growth in UHV TEM was conducted at 650 °C, with C₂H₂ being leaked continuously into the microscope column to maintain a backfilled pressure of ~8 × 10⁻⁶ Torr. In order to minimize...
the influence of electron beam on the growth process, the electron beam intensity was kept between 0.1 and 0.3 A/cm². Postdeposition inspection of C nanostructures showed no significant differences between irradiated and nonirradiated areas. The final carbon products formed in the TEM were strongly dependent upon the shape and size of the Ni catalyst supported on MgO. Among them, small Ni crystallites (<6 nm) catalyze the growth of the SWNTs through the base growth mode. Larger Ni particles, particularly with diameter ranging from 7 to 30 nm, tend to form mostly carbon nanocages and a few isolated MWNT/BCNT. Detailed information on the catalyst preparation and experimental procedures has been reported elsewhere. On the basis of direct in situ experimental data, we elucidate the mechanism of both complete and incomplete knot formation in BCNT. The growth of a complete inner graphene layer prior to contraction of the Ni catalyst particle due to restoring cohesive forces will result in a complete BCNT knot whereas partial growth of the inner wall will lead to an incomplete BCNT knot. Our experiment and observation on heterogeneous gas–solid based reaction is different from those of solid–solid/liquid (carbon–metal) route for the formation of CNTs. We believe the mechanism proposed here is representative of BCNT growth via CVD methods.

BCNTs are relatively straight-sided tubes divided into sections by “knots” made from single or multiple graphene sheets. From the morphological perspective, we can group the BCNT knots into two categories: (i) complete and (ii) incomplete knots. Figure 1a shows a typical BCNT grown by CVD ex situ in a furnace for high volume production. It has complete knots whereby the inner graphene compartment layers are fully formed, extended, and have bridged the inner diameter of the outer tube. Figure 1b shows, on the other hand, an incomplete bamboo knot structure. In order to rationalize the difference in BCNT morphology and to control the types of BCNT structure formed during growth, i.e., complete or incomplete BCNT knots, we need to probe the BCNT growth mechanism.

The growth dynamics of BCNT were probed in situ using a sequence of bright-field images, taken at intervals of 6 s during exposure of the catalyst to C₂H₂ at an elevated temperature of 650 °C. Figure 2 shows a series of consecutive TEM images showing the formation of a knot in a BCNT catalyzed by a 12 nm Ni particle in real time (See Supporting Information, movie 1 (nl070681xsi20070528_071111.gif), which is grouped by a series of TEM images at 5 frames per second. One second in the video equals 30 s in the real experiment). Although the thermal vibration at 650 °C of the unsupported extended segment makes the images slightly unclear, we are still able to measure the length and thickness of the graphene wall and hence calculate both the number of graphene layers and the growth rate as function of time. The following important stages during growth were observed.

(i) The growth of this CNT does not start instantaneously upon opening the C₂H₂ leak valve. There is a time lag of 774 s before tube growth is observed.

(ii) The growth mode is tip-based. The catalyst particle remains as crystalline metallic Ni at 650 °C during the growth process (see Figure 1 in Supporting Information). Therefore, the mechanism of CNT growth is not through C precipitation from Ni₃C but rather through the diffusion of C adatoms...
followed by nucleation and growth. There are two possible
diffusion pathways, i.e., bulk diffusion and surface diffusion
to the boundary of the Ni—graphene growth interface for
growth of the outer graphene layer, with the latter dominating
the reaction pathway due to a lower activation energy barrier
and lower coordination number. For growth of inner graphene
layers, we expect the interfacial diffusion of C adatom
through the Ni—graphene edges/interface as the dominating
route.

(iii) The front of the Ni particle has no graphene coating.
Graphene layers parallel to the growth axis of the nanotube
nucleate at the base of the symmetric Ni catalyst particle.
The increase in the tube length thereafter is due to incorpora-
tion and attachment of C adatoms through surface diffusion
to the multistep graphite—Ni edges. At this point the thickness
of the carbon wall is ≈1.67 nm, corresponding to five
graphene layers. The instantaneous growth rate measured is
≈0.34 nm s⁻¹ (incorporation of ≈2500 C atoms per second).

(iv) As more C is added to the end of the graphene layers
the Ni catalyst particle becomes asymmetric and the nuclea-
tion steps expand to become broader at the upper edge
(indicated by the arrow in Figure 2c), as shown in parts b
and c of Figure 2. This indicates the onset of the formation
of the BCNT knot. Another five new graphene layers parallel
to the as grown C walls are nucleated, resulting in a thicker
wall as shown in Figure 2d. The newly formed layers are
not observed on both sides of the Ni particle, indicating that
the new graphite layers are asymmetric and do not encircle
the whole Ni particle.

(v) As growth continues, the five newly nucleated graphene
layers grow and extend around the bottom of the catalyst
particle, thus forming a hemispherical cap within the
nanotube and sealing the existing tube internally. This results
in the formation of the knot in the BCNT, which fully
encapsulates the lower part of the catalyst particle (panels
e—g of Figure 2).

(vi) During BCNT formation, the effective diameter of
the base of the catalyst shrinks, resulting in elongation of the
Ni catalyst particle. This increases the effective surface
and interface area of Ni catalyst particle. The elastic
elongation also increases the strain energy of the catalyst.

(vii) The Ni particle contracts and is ejected from the
newly formed bamboo knot. The complete growth process,
i.e., (ii—vii) repeats yielding a complete BCNT with multiple
knots along its length.

Nanostructures grown by CVD growth can be categorized into
tip- and base-growth modes. This classification is based on
the initial catalyst particle position prior to growth. For tip
growth, the catalyst particle and the growth front move with
respect to the initial catalyst position, whereas in the base-
growth mode, C incorporation into graphene results in the
walls being pushed away from the stationary catalyst to form
the tubular structure. The growth front, in both cases, is at the
catalyst—tube interface as shown in parts a and b of
Figure 3. The nucleation and growth of CNT follow the
adsorption—decomposition—surface diffusion—nucleation pro-
cess. Nucleation and incorporation of C atoms into the
growing graphite walls are driven by energetic consider-
ations. Hemispherical caps are found in the initial
growth and nucleation of single-walled carbon nanotubes;
similarly for the tip growth of MWNTs, closed caps have
also been observed at some of the roots nanotubes (Sup-
porting Information, Figure 2). It is interesting to note that
when the leak valve is opened, we do not observe the
immediate growth of CNTs. Instead, there is a period of
≈774 s where there is no discernible elongation of CNTs.
Drawing on an analogy to the incubation period for critical
nuclei in crystal growth, the initial formation of the hemi-
spherical cap (precursor to the formation of the CNT outer
wall) on the Ni catalyst is thus the slow step in the growth
of the nanotube. Assuming an attempt frequency of 10¹³ s⁻¹,
the estimated nucleation barrier for C adatoms to form the
circular cap at 650 °C is 2.91 eV.

Once an initial graphene layer forms on the Ni particle,
the C adatoms on the Ni surface can further lower the system
energy through incorporation into graphene layers. The
elongation thereafter is due to the incorporation and attach-
ment of C adatoms to the interface between the initial
graphene layer and the catalyst particle by surface diffusion
of C adatoms on the metallic Ni catalyst. From our
observations, the growth of graphene layers occurs prefer-
entially at the Ni surface multistep edges, where the graphene
layers at the end of the nanotube are in contact with the Ni
particle, as shown in Figure 2. The fact that we do not
observe the nucleation of graphene fragments on other
exposed Ni surfaces during the whole growth process further
suggests that the multistep edge site is the preferred growth
front. It has been noted that the diffusion through the
graphene layers is energetically unfavorable with energy > 10
eV. Therefore, the most probable C source for growth of

Figure 3. Schematic diagram showing (a) the growth of a CNT via the base-growth mode; (b) the growth of a CNT via the tip-
growth mode; (c) the nucleation of a partial bamboo-knot graphite sheet at the graphene wall-catalyst junction; (d) the growth of the
inner wall around the bottom of the Ni catalyst particle as adatoms are added to the inner wall edges through diffusion along the
graphene—Ni interface; (e) subsequent formation of a hemispherical cap around the bottom of the catalyst particle. (Arrows indicate
the direction of movement of the graphite relative to the Ni—
graphite step edges; (e), (f), and (g) show formation of an incomplete knot.
inner graphene layers is through interfacial diffusion, where carbon atoms diffuse through the Ni–graphene interface at the multistep edge. Analogous to the phase boundary between two material systems, the interface provides a low-energy diffusion pathway for surface C adatoms to diffuse through and be incorporated into the growing inner graphene layers at the multistep edge. The growth is also complemented by direct bulk diffusion through Ni catalyst. However, we believe the latter is the minor diffusion pathway as the barrier is higher. During growth, the Ni multistep edges recede while the graphene sheet advances and the shape of the catalyst is always changing. This results in continuous elongation of the catalyst particle along the direction of growth. The elastic elongation of the catalyst caused by reduced internal radius of the tube increases its strain energy. Therefore, this suggests that the increase in graphene–Ni interfacial energy and strain energy during graphene layer formation is offset by the reduction in energy needed in forming graphene layers from an aggregate of isolated C adatoms on the Ni surface, when the tube is constrained to grow.

At the onset of formation of the bamboo-like structure, the growth front at the Ni–graphite steps abruptly changes into a two-step growth process (Figure 3). Step A yields the outer graphene wall, while step B forms the inner hemispherical cap round the base of the Ni particle. In both cases, the growth front still remains at the multistep edge. At the step A edge, the outer graphene layers continue to grow through the receding Ni step edges elongating the tube. Whereas at the step B edge, an extra graphene layer nucleates at the inner edge of the external tube wall next to the catalyst particle (indicated by arrow B in Figure 3c). This site is preferred because it is stabilized by interaction with both the external graphene wall and the Ni catalyst particle surface.\(^{25}\) The graphene–graphene interplaner cohesive energy is \(\sim 0.042 \text{ eV/atom}\)\(^{23}\) and the graphene–Ni binding energy \(\sim 0.05 \text{ eV/atom}\).\(^{26}\) Once the inner graphene sheet nucleates at the step B edge, C adatoms are continuously added to the inner walls edges through interfacial diffusion along the graphene–Ni interface.\(^{15}\) The inner wall quickly grows around the bottom of the Ni catalyst particle, resulting in the formation of a hemispherical cap around the bottom of the catalyst particle. There are two possible pathways by which the inner wall can grow: (i) the C atoms continuously attach to the inner graphene layer at the multistep edge, resulting in the inner graphene layer being pushed away from the multistep edge and sliding round to encircle the bottom of the catalyst and (ii) C atoms diffuse along the Ni–graphene interface and add to the end of the inner graphene layer that is furthest away from the Ni multistep edge, requiring no sliding but a longer diffusion path. For both mechanisms the inner wall quickly grows around the bottom of the Ni catalyst particle, resulting in the formation of a hemispherical cap. Unfortunately in our experiments, we are not able to discern between these two mechanisms as this would require a tracer on the inner graphene layer.

From the growth perspective, considering the growth of the outer carbon walls, the growth front moves upward with reference to the static outer wall, like for the conventional tip-growth process where the catalyst particle moves with respect to the growth front. Growth of the BCNT knot, using the growth front at step B as a reference, therefore appears to follow the convention of base growth where the apparent inner tube growth direction is opposite of the other tube, as indicated in parts c and d of Figure 3. The completion of step B growth before the contraction of the Ni catalyst particle due to the restoring cohesive forces will result in a complete BCNT knot as illustrated in Figure 1a, whereas partial growth of the inner wall will lead to incomplete BCNT knots. Figure 4 shows a sequence of bright-field TEM images of an incomplete BCNT knots growth process. The rapid contraction of the Ni catalyst before the completion of growth of inner layers, results in leaving a partial knot behind. (Video 2 (l07068111si20070528_0712111.gif) in Supporting information gives another example of incomplete knot formation.) This process is illustrated schematically in parts f–h in Figure 3. In order to form BCNT structures with complete knots in a controlled manner, the relative growth rate of the outer graphene layer and the inner BCNT layers is therefore of importance for kinetic considerations. We would expect complete BCNT knots to form if the contraction of the Ni catalyst particle occurs after the growth of the inner hemispherical cap is completed.

In summary, we have used in situ TEM to probe the growth mechanism of the BCNT structure, in particular the knot formation process. The catalyst particle remains metallic and crystalline during exposure to C\(_2\)H\(_2\). Therefore, BCNT growth follows the adsorption–decomposition–surface diffusion–step nucleation process instead of a precipitation reaction. During BCNT growth, the shape of the catalyst particle changes constantly. The BCNT knot preferentially nucleates on the multistep Ni–graphite edges, at the graphene wall–catalyst junction, as it is stabilized by both the graphene walls and the Ni catalyst surface. A complete inner graphene layer growth prior to contraction of the Ni catalyst particle due to restoring cohesive forces will result in a complete BCNT knot whereas partial growth of the inner wall will lead to an incomplete BCNT knot.

![Figure 4](image-url). A sequence of TEM images showing the formation of an incomplete knot in less than 6 s. The fast restoring action of Ni catalyst leaves an incomplete knot behind. White arrows indicate where knot is formed. The time on (c)–(f) is referenced to frame (a), which is set to 0 s.
Supporting Information Available: Figures showing a selected area diffraction pattern of Ni-MgO catalyst during and after CNT growth and bright field TEM images of BCNTs and videos showing the formation of complete and incomplete BNCT knots. This material is available free of charge via the Internet at http://pubs.acs.org.

References

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